NSN 5961-00-105-9019

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-105-9019 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.231 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.5 forward voltage, average **Current Rating Per Characteristic:** 6.00 milliamperes forward current, total rms peak **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 97942-580r082h01 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0